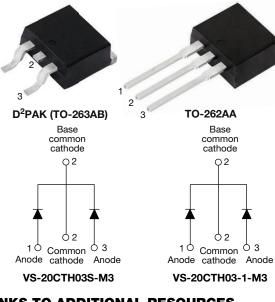


## VS-20CTH03S-M3, VS-20CTH03-1-M3

**Vishay Semiconductors** 

## Hyperfast Rectifier, 2 x 10 A FRED Pt®



## LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 10 A					
V <sub>R</sub>	300 V					
V <sub>F</sub> at I <sub>F</sub>	0.85 V					
t <sub>rr</sub> max.	35 ns					
T <sub>J</sub> max.	175 °C					
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

## FEATURES

- Hyperfast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Meets JESD 201, class 1A whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

Vishay Semiconductors 300 V series are the state of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

### **MECHANICAL DATA**

**Case:** D<sup>2</sup>PAK (TO-263AB), TO-262AA

Molding compound meets UL 94 V-0 flammability rating **Terminal:** matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Peak repetitive reverse voltage		V <sub>RRM</sub>		300	V		
Average rectified forward current	per diode	1	T <sub>C</sub> = 160 °C	10			
Average rectilied forward current	per device	IF(AV)		20	А		
Non-repetitive peak surge current		I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	120			
Operating junction and storage tem	peratures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 100 μA	300	-	-		
Forward voltage	V	I <sub>F</sub> = 10 A	-	1.05	1.25	V	
	V <sub>F</sub>	I <sub>F</sub> = 10 A, T <sub>J</sub> = 125 °C	-	0.85	0.95		
Poverse leakage aurrent	I <sub>R</sub>	$V_{R} = V_{R}$ rated	-	-	20		
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	6	200	μA	
Junction capacitance	CT	V <sub>R</sub> = 300 V	-	30	-	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8	-	nH	

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## VS-20CTH03S-M3, VS-20CTH03-1-M3

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_c = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	YMBOL TEST CONDITIONS MIN. TYP. MAX.					UNITS
Reverse recovery time		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$	50 A/µs, V <sub>R</sub> = 30 V	-	-	35	
	+	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$			30	200
	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	31	-	A
		T <sub>J</sub> = 125 °C		-	42	-	
Deels receivers ourrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	$I_{\rm F} = 10  {\rm A}$	-	2.4	-	
Peak recovery current		T <sub>J</sub> = 125 °C	dl <sub>F</sub> /dt = 200 A/µs V <sub>B</sub> = 200 V	-	5.6	-	
Poweree receivery charge	0	T <sub>J</sub> = 25 °C		-	36	-	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	120	-	nC

THERMAL - MECHANICAL	THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C			
Thermal resistance, junction to case per diode	R <sub>thJC</sub>		-	-	1.5	°C/W			
Thermal resistance, junction to ambient	R <sub>thJA</sub>		-	-	70	°C/W			
Weight			-	2.0	-	g			
Weight			-	0.07	-	oz.			
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)			
Marking davias		Case style D <sup>2</sup> PAK (TO-263AB) 20CTH03							
Marking device		Case style TO-262AA	20CTH03-1						

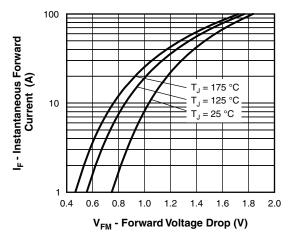


Fig. 1 - Maximum Forward Voltage Drop Characteristics

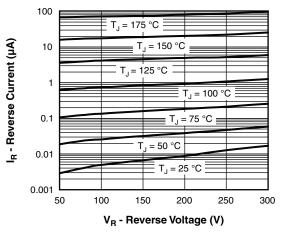


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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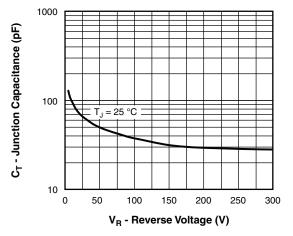


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

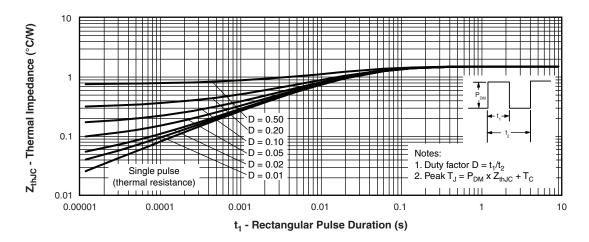


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

Average Power Loss (W)

20

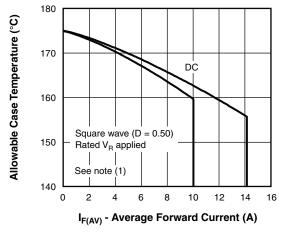


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

#### Note

 $^{(1)} \mbox{ Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \mbox{forward power loss} = I_{F(AV)} \times V_{FM} \mbox{ at } (I_{F(AV)}/D) \mbox{ (see fig. 6); } \\ Pd_{REV} = \mbox{inverse power loss} = V_{R1} \times I_R \mbox{ (1 - D); } I_R \mbox{ at } V_{R1} = \mbox{rated } V_R \mbox{ at } V_{R1} = \mbox{rated } V_R \mbox{ at } V_{R1} \$ 

16 RMS limit 12 D = 0.01 8 D = 0.02D = 0.05 D = 0.104 D = 0.20 DC D = 0.50 0 0 2 4 6 8 10 12 14 16 I<sub>F(AV)</sub> - Average Forward Current (A)

Fig. 6 - Forward Power Loss Characteristics

Document Number: 96386

Revision: 21-Dec-2021

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## VS-20CTH03S-M3, VS-20CTH03-1-M3

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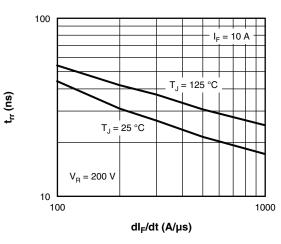


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

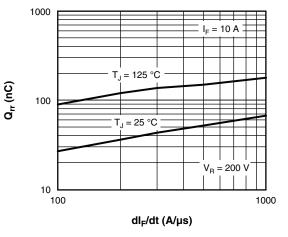


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

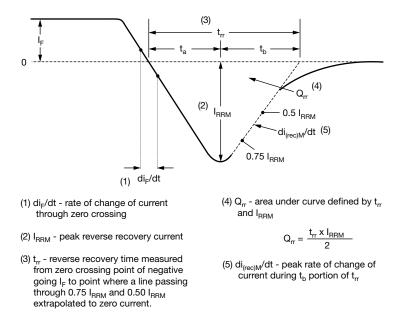
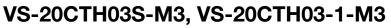


Fig. 9 - Reverse Recovery Waveform and Definitions

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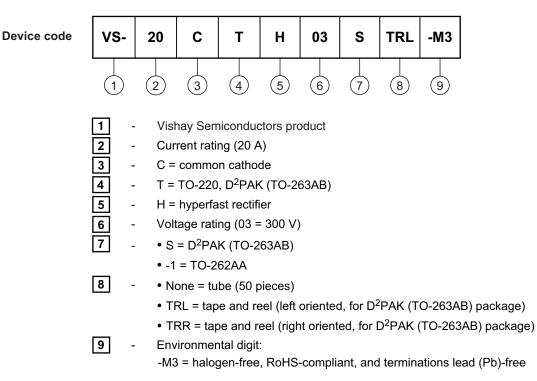


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## **Vishay Semiconductors**

### ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)						
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-20CTH03S-M3	50	Antistatic plastic tubes				
VS-20CTH03STRL-M3	800	13" diameter plastic tape and reel				
VS-20CTH03STRR-M3	800	13" diameter plastic tape and reel				
VS-20CTH03-1-M3	50	Antistatic plastic tubes				

LINKS TO RELATED DOCUMENTS						
Dimensions	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96164				
	TO-262AA	www.vishay.com/doc?96165				
Part marking information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444				
Fart marking information	TO-262AA	www.vishay.com/doc?95443				
Packaging information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96424				
SPICE model		www.vishay.com/doc?96583				

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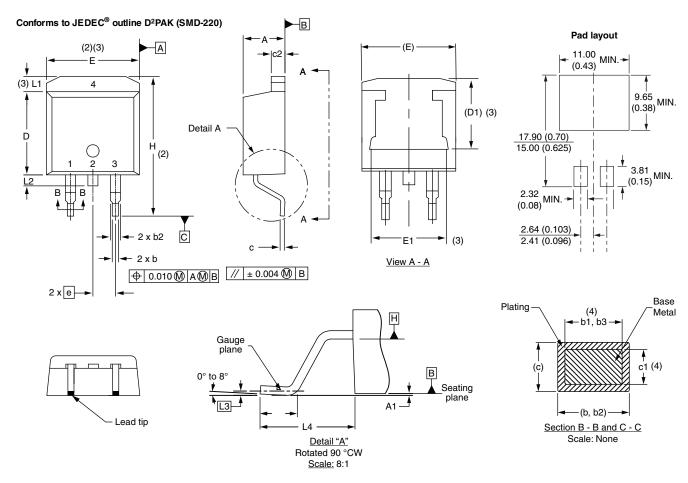


# **Outline Dimensions**

**Vishay Semiconductors** 

D<sup>2</sup>PAK

## **DIMENSIONS** in millimeters and inches



SYMBOL	ETERS	INC	INCHES	NOTES	NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES	
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		STINDUL	MIN.	MAX.	MIN.	MAX.	NUTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inches

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

### Revision: 13-Jul-17

Document Number: 96164

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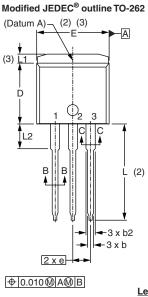


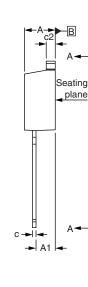
# **Outline Dimensions**

**Vishay Semiconductors** 

# **TO-262AA**

## **DIMENSIONS** in millimeters and inches



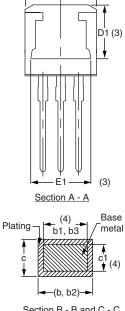


Lead assignments

Lead tip



1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode



F

Section B - B and C - C Scale: None

	MILLIN	IETERS	INC	NOTEO	
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	) BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

#### Notes

 (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body (3)

Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only (5)

Controlling dimension: inches Outline conform to JEDEC<sup>®</sup> TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), (6) L1 (max.), L2 (min., max.)

#### Revision: 30-Nov-17 1 Document Number: 96165 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000





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